

## 500mA, 3.3V Linear Regulator with Auxiliary Control

### Description

The CS5231-3 combines a three-terminal linear regulator with circuitry controlling an external PFET transistor thus managing two input supplies. The part provides a 3.3V regulated output either from the main 5V supply or a 3.3V auxiliary that switches on when the 5V supply is not present. This delivers constant, uninterrupted power to the load. The CS5231-3 meets Intel's "Instantly Available" power requirements which follows from the "Advanced Configuration and Power Interface" (ACPI) standards developed by Intel, Microsoft and Toshiba.

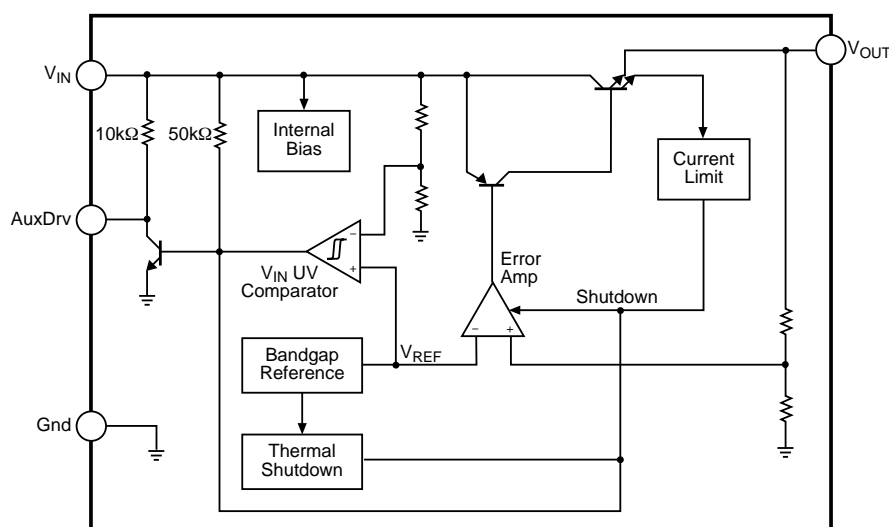
The CS5231-3 linear regulator provides a fixed 3.3V output at 500mA with an overall accuracy of  $\pm 2\%$ . The internal NPN-PNP composite pass transistor provides a low dropout voltage and requires less supply current than a straight PNP design. Full protection with both current limit and thermal shutdown is provided.

Designed for low reverse current, the IC prevents excessive current from flowing from  $V_{OUT}$  to either  $V_{IN}$  or ground when the regulator input voltage is lower than the output voltage.

The CS5231-3 can be used to provide power to an ASIC on a PCI Network Interface Card (NIC). When the system enters a Sleep State and the 5V input drops below 4.4V, the AuxDrv control signal on the CS5231-3 is activated turning on the external PFET. This switches the supply source from the 5V input to the 3.3V input through the PFET, guaranteeing a constant 3.3V output to the ASIC that is "glitch free."

The CS5231-3 is available in two package types: the 5-Lead D<sup>2</sup> PAK (TO263) package and the 8-Lead SOIC 4Lead-fused (DF) package. Other applications include desktop computers, power supplies with multiple input sources and PCMCIA/PCI interface cards.

### Block Diagram



### Features

#### Linear Regulator

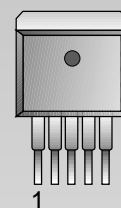
- 3.3V  $\pm 2\%$  Output Voltage
- 3mA Quiescent Current @ 500mA
- Fast Transient Response
- Current Limit Protection
- Thermal Shutdown with Hysteresis
- 450 $\mu$ A Reverse Output Current

#### System Power Management

- Auxiliary Supply Control
- "Glitch Free" Transition Between Two Supplies

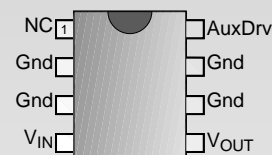
### Package Options

#### 5 Lead D<sup>2</sup>PAK



1. No Connect
  2.  $V_{IN}$
  3. Gnd
  4.  $V_{OUT}$
  5. AuxDrv
- Tab = Gnd

#### 8 Lead SO Narrow (Internally Fused Leads)



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## Absolute Maximum Ratings

Maximum Operating Junction Temperature .....	150°C
Storage Temperature Range .....	-65°C to +150°C
Lead Temperature Soldering	
Reflow (SMD styles only) .....	60 sec. max above 183°C, 230°C peak
ESD Damage Threshold (Human Body Model) .....	2kV

PIN SYMBOL	PIN NAME	V <sub>MAX</sub>	V <sub>MIN</sub>	I <sub>SOURCE</sub>	I <sub>SINK</sub>
V <sub>IN</sub>	IC Power Input	14V	-0.3V	100mA	Internally Limited
V <sub>OUT</sub>	Output Voltage	6V	-0.3V	Internally Limited	100mA
AuxDrv	Auxiliary Drive Output	14V	-0.3V	10mA	50mA
Gnd	IC Ground	N/A	N/A	N/A	N/A

**Electrical Characteristics:** 0°C < T<sub>A</sub> < 70°C, 0°C < T<sub>J</sub> < 125°C, 4.75V ≤ V<sub>CC</sub> < 6V, C<sub>OUT</sub> ≥ 10μF with ESR < 1Ω, I<sub>OUT</sub> = 10mA, unless otherwise specified.

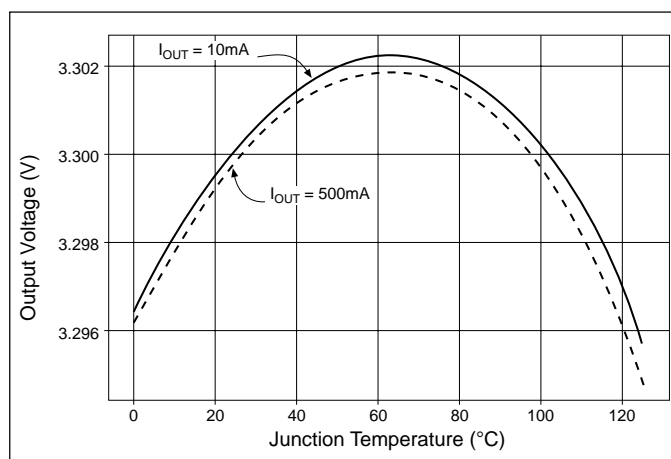
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>■ Linear Regulator</b>					
Output Voltage	10mA < I <sub>OUT</sub> < 500mA	3.234 -2%	3.300	3.366 +2%	V
Line Regulation	I <sub>OUT</sub> = 10mA, V <sub>IN</sub> = 4.75V to 6V		1	5	mV
Load Regulation	V <sub>IN</sub> = 5V, I <sub>OUT</sub> = 10mA to 500mA		5	15	mV
Ground Current	I <sub>OUT</sub> = 10mA I <sub>OUT</sub> = 500mA		2 3	3 6	mA mA
Reverse Current	V <sub>IN</sub> = 0V, V <sub>OUT</sub> = 3.3V		0.45	1	mA
Current Limit	0V < V <sub>OUT</sub> < 3.2V	0.55	0.85	1.2	A
Thermal Shutdown	Note 1	150	180	210	°C
Thermal Shutdown Hysteresis	Note 1		25		°C
<b>■ Auxiliary Drive</b>					
Upper V <sub>IN</sub> Threshold	Increase V <sub>IN</sub> until regulator turns on and AuxDrv drives high	4.35	4.5	4.65	V
Lower V <sub>IN</sub> Threshold	Decrease V <sub>IN</sub> until regulator turns off and AuxDrv drives low	4.25	4.4	4.55	V
V <sub>IN</sub> Threshold Hysteresis		75	100	125	mV
Output Low Voltage	I <sub>AuxDrv</sub> = 100μA, 1V < V <sub>IN</sub> < 4.5V		0.1	0.4	V
Output Low Peak Voltage	Increase V <sub>IN</sub> from 0V to 1V. Record peak AuxDrv output voltage		0.65	0.9	V
AuxDrv Current Limit	V <sub>AuxDrv</sub> = 1V, V <sub>IN</sub> = 4.0V	0.5	6	25	mA
Response Time	Step V <sub>IN</sub> from 5V to 4V, measure time for V <sub>AuxDrv</sub> to drive low. Note 1		1	10	μs
Pull-Up/Down Resistance	V <sub>IN</sub> = 0V and V <sub>IN</sub> > 4.7V	5	10	25	kΩ

Note 1: Guaranteed by design, not 100% production tested. Thermal shutdown is 100% functionally tested at wafer probe.

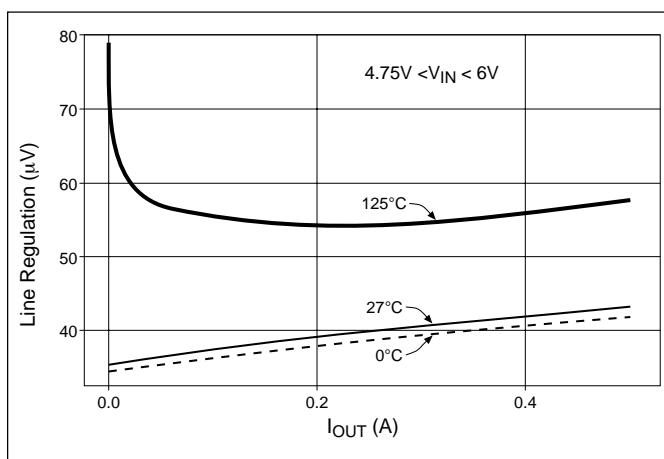
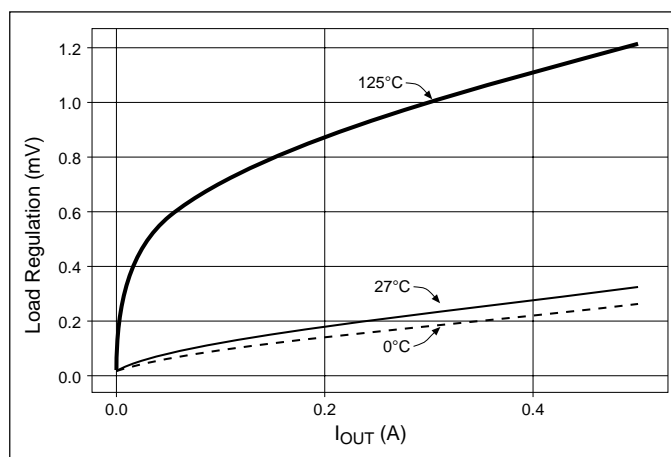
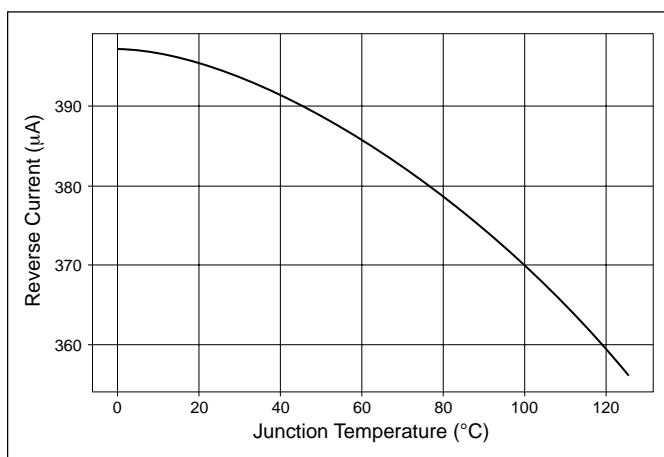
## Package Pin Description

PACKAGE PIN #	PIN SYMBOL	FUNCTION
<b>5 Lead D<sup>2</sup> PAK      8 Lead SO Narrow</b> <b>(Internally Fused Leads)</b>		
1	1	NC
2	4	V <sub>IN</sub>
3, Tab	2, 3, 6, 7	Gnd
4	5	V <sub>OUT</sub>
5	8	AuxDrv
		Output used to control an auxiliary supply voltage. This lead is driven low if V <sub>IN</sub> is less than 4.5V, and is otherwise pulled up to V <sub>IN</sub> through an internal 10kΩ resistor.

## Typical Performance Characteristics

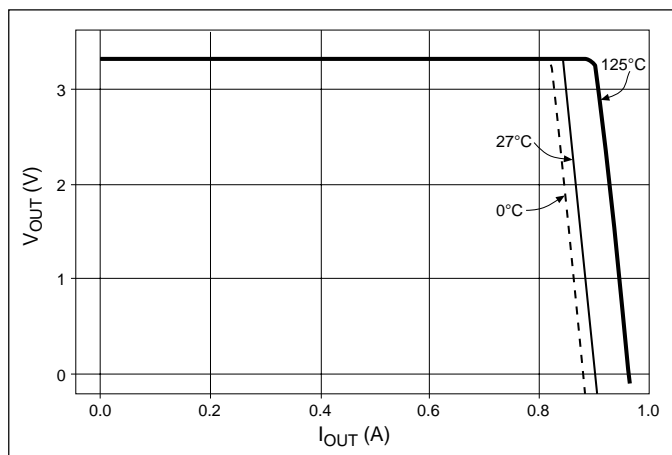
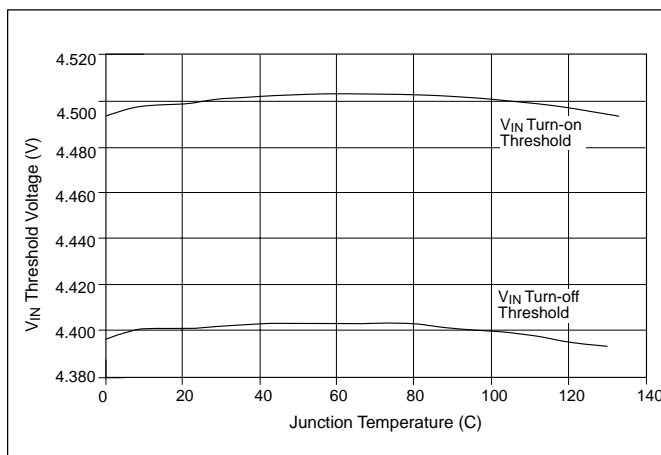
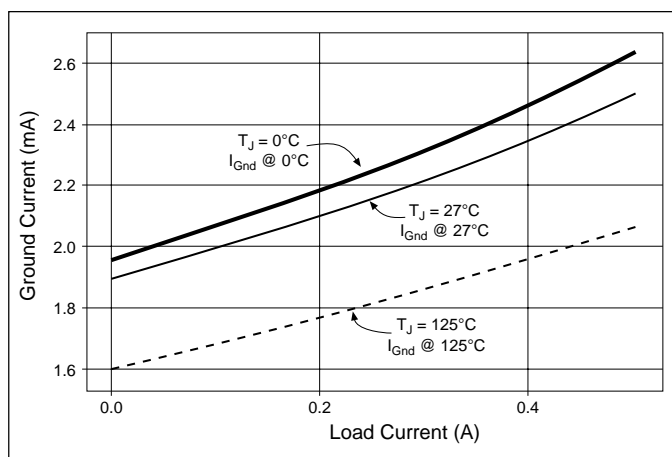


Output Voltage vs. Junction Temperature

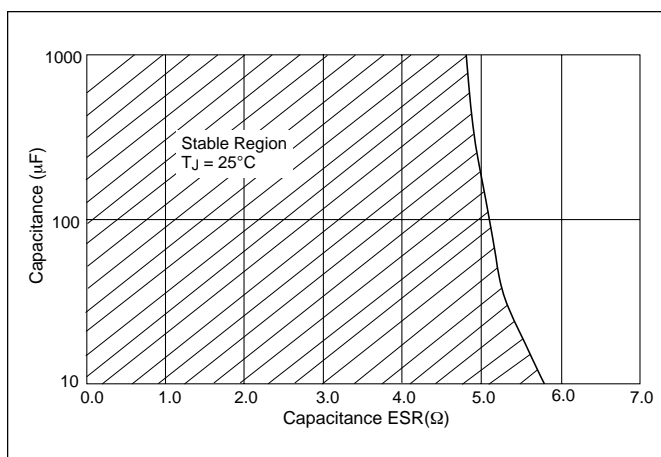
Line Regulation vs. I<sub>OUT</sub> Over TemperatureLoad Regulation vs. I<sub>OUT</sub> Over Temperature

Reverse Current vs. Junction Temperature

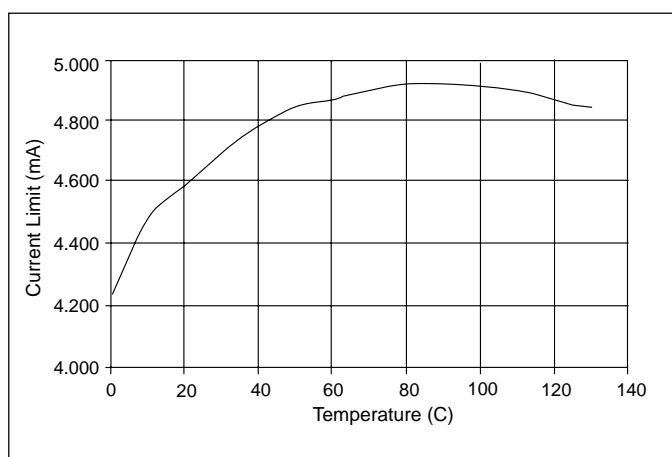
## Typical Performance Characteristics: continued

 $V_{OUT}$  vs.  $I_{OUT}$  Over Junction Temperature $V_{IN}$  Thresholds vs. Junction Temperature

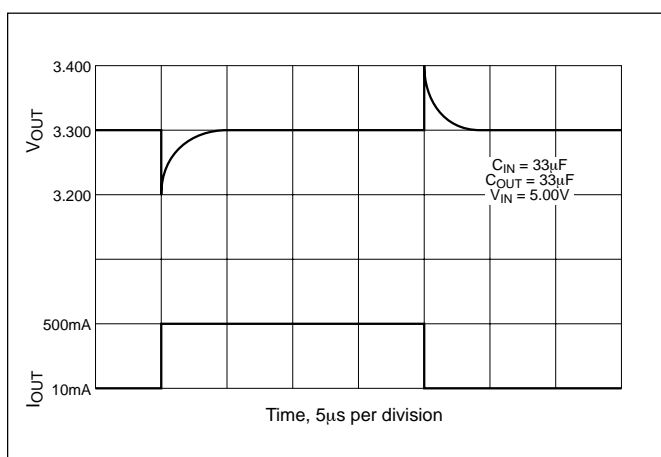
Ground Current vs. Load Current



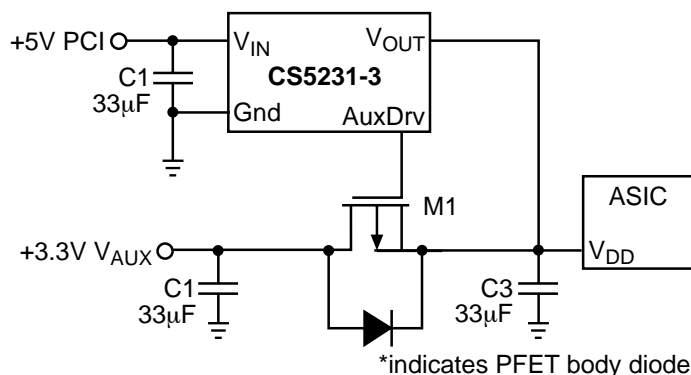
Region of Stable Operation



AuxDrv Current Limit vs. Junction Temperature



Transient Response



## Application Information

## Theory of Operation

The CS5231-3 is a fixed 3.3V linear regulator that contains an auxiliary drive control feature. When  $V_{IN}$  is greater than the typical 4.5V threshold, the IC functions as a linear regulator. It provides up to 500mA of current to a load through a composite PNP-NPN pass transistor. An output capacitor greater than  $10\mu\text{F}$  with equivalent series resistance less than  $1\Omega$  is required for compensation. More information is provided in the Stability Considerations section.

The CS5231-3 provides an auxiliary drive feature that allows a load to remain powered even if the  $V_{IN}$  supply for the IC is absent. An external p-channel FET is the only additional component required to implement this function if an auxiliary power supply is available. The PFET gate is connected to the AuxDrv lead. The PFET drain is connected to the auxiliary power supply, and the PFET source is connected to the load. The polarity of this connection is very important, since the PFET body diode will be connected between the load and the auxiliary supply. If the PFET is connected with its drain to the load and its source to the supply, the body diode will be forward-biased if the auxiliary supply is turned off. This will result in the linear regulator providing current to everything on the auxiliary supply rail.

The AuxDrv lead is internally connected to a  $10\text{k}\Omega$  resistor and to a saturating NPN transistor that acts as a switch. If the  $V_{IN}$  supply is off, the AuxDrv output will connect the PFET gate to ground through the  $10\text{k}\Omega$  resistor, and the PFET will conduct current to the load.

As the  $V_{IN}$  supply begins to rise, the AuxDrv lead will also rise until it reaches a typical voltage of about 650mV. The NPN transistor connected to the AuxDrv lead will saturate at this point, and the gate of the PFET will be pulled down to a typical voltage of about 100mV. The PFET will continue to conduct current to the load.

The  $V_{IN}$  supply voltage will continue to rise, but the linear regulator output is disabled until  $V_{IN}$  reaches a typical threshold of 4.5V. During this time, the load continues to be powered by the auxiliary driver. Once the 4.5V  $V_{IN}$  threshold is reached, the saturating NPN connected to the AuxDrv lead turns off. The on-chip  $10\text{k}\Omega$  pull-up resistor will pull the PFET gate up to  $V_{IN}$ , thus turning the PFET off. The linear regulator turns on at the same time. An

external compensation capacitor is required for the linear regulator to be stable, and this capacitance also serves as a charge reservoir to minimize any “glitching” that might result during the supply changeover. Hysteresis is present in the AuxDrv circuitry, requiring  $V_{IN}$  to drop by 100mV (typical) after the linear regulator is providing power to the load before the AuxDrv circuitry can be re-enabled.

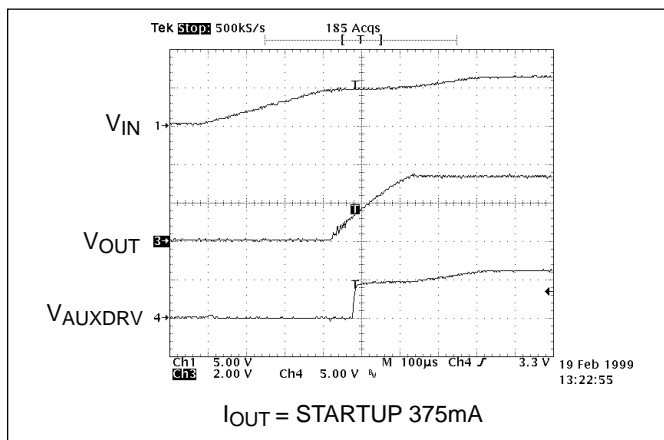


Figure 1. Initial power-up,  $V_{AUX}$  not present  $R_{OUT} = 8.8\Omega$ .

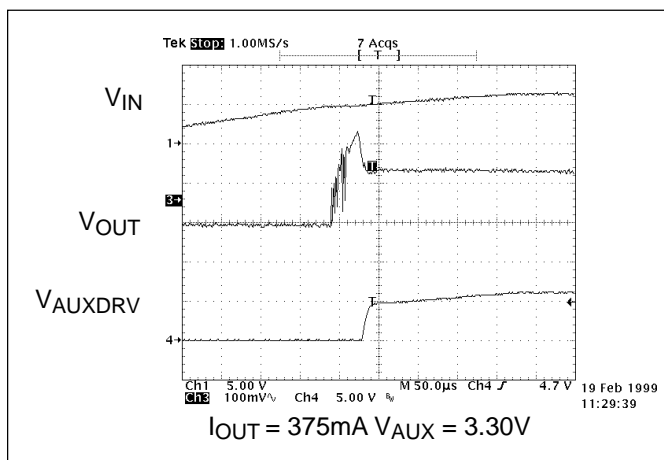


Figure 2a. Power-up,  $V_{AUX} = 3.30\text{V}$ . Note the “oscillatory performance” as the linear regulator charges the  $V_{OUT}$  node.  $I_{OUT} \times R_{DS(ON)} \approx 130\text{mV}$

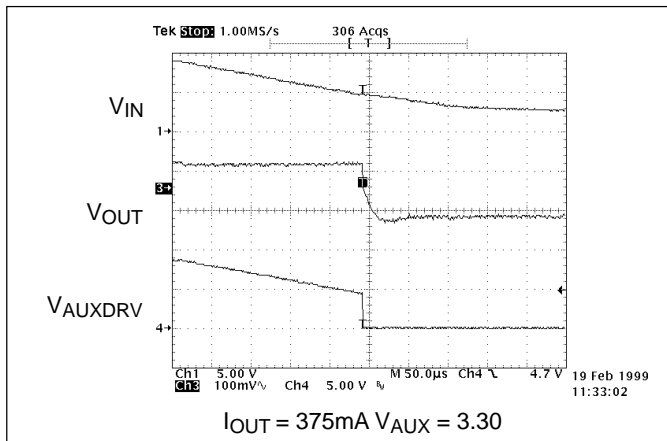


Figure 2b. Power-down,  $V_{AUX} = 3.30V$ . Again, note  $\Delta V = I_{OUT} R_{DS(ON)} \approx 130mV$ .

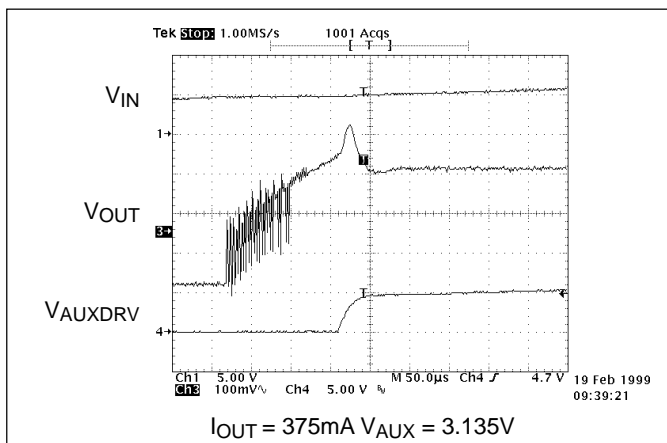


Figure 3a. Power-up,  $V_{AUX} = 3.135V$ . The "oscillatory performance" mode lasts longer because the difference between  $V_{AUX}$  and 3.30 is greater.

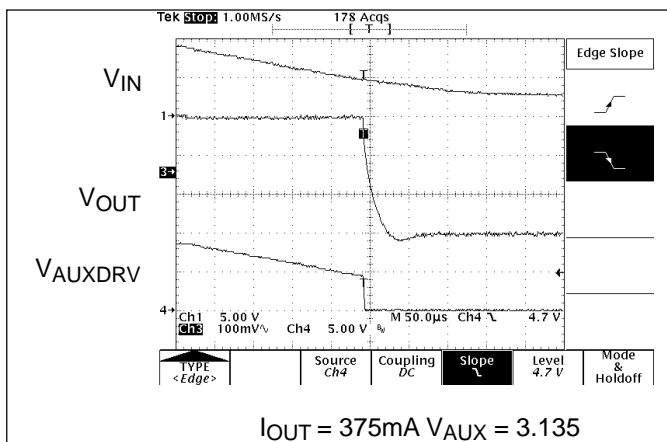


Figure 3b. Power-down,  $V_{AUX} = 3.135V$ . The difference in voltage is now  $I_{OUT} \times R_{DS(ON)}$  plus the difference in supply voltages ( $3.30 - V_{AUX}$ ).

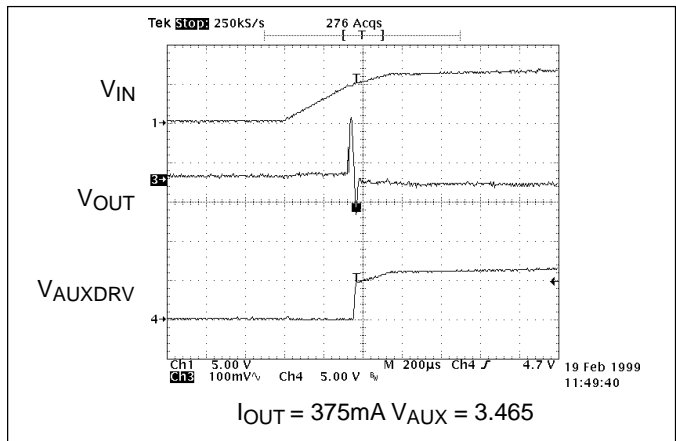


Figure 4a. Power-up,  $V_{AUX} = 3.465V$ .  $I_{OUT} \times R_{DS(ON)}$  is compensated by the higher value of  $V_{AUX}$ .

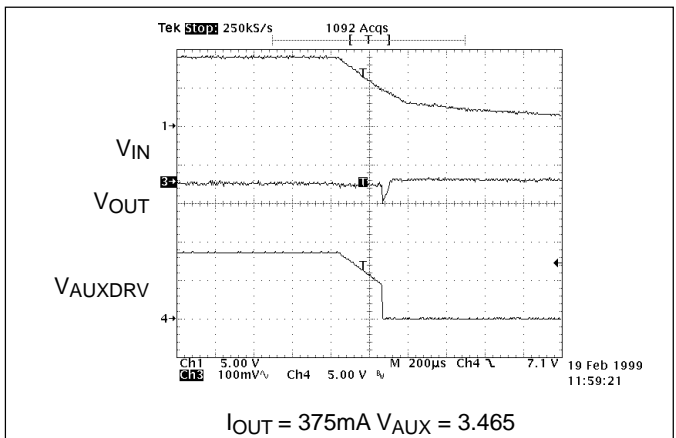


Figure 4b. Power-down,  $V_{AUX} = 3.465V$ .

### Stability Considerations

The output capacitor helps determine three main characteristics of a linear regulator: startup, transient response and stability.

Startup is affected because the output capacitor must be charged. At initial startup, the  $V_{IN}$  supply may not be present, and the output capacitor will be charged through the PFET. The PFET will initially provide current to the load through its body diode. The diode will act as a voltage follower until sufficient voltage is present to turn the FET on. Since most commercial power supplies have a fairly low ramp rate, charging through the body diode should effectively limit in-rush current to the capacitor.

During normal operation, transient load current requirements will be satisfied from the charge stored in the output capacitor until either the linear regulator or the auxiliary supply can respond. Larger values of capacitance will improve transient response, but will also cost more. A linear regulator will respond within microseconds, where an external power supply may take milliseconds to react. The output capacitance will provide the difference in current until this occurs. The result will be an instantaneous voltage change at the output. This change is the product of the current change and the capacitor ESR:

$$\Delta V_{OUT} = (\Delta I_{LOAD}) (ESR)$$

This limitation directly affects load regulation. Capacitor ESR must be minimized if output voltage must be maintained within tight tolerances. In such a case, it is often advisable to use a parallel network of different types of capacitors. For example, electrolytic capacitors provide high charge storage capacity in a small size, while tantalum capacitors have low ESR. The parallel combination will result in a high capacity, low ESR network. It is also important to physically locate the capacitance network close to the load, and to connect the network to the load with wide PC board traces to minimize the metal resistance.

The CS5231-3 has been carefully designed to be stable for output capacitances greater than 10 $\mu$ F with equivalent series resistance less than 1 $\Omega$ . While careful board layout is important, the user should have a stable system if these constraints are met. A graph showing the region of stability for the CS5231-3 is included in the "Typical Performance Characteristics" section of this data sheet.

#### Input Capacitors and the $V_{IN}$ Thresholds

A capacitor placed on the  $V_{IN}$  pin will help to improve transient response. During a load transient, the input capacitor serves as a charge "reservoir", providing the needed extra current until the external power supply can respond. One of the consequences of providing this current is an instantaneous voltage drop at  $V_{IN}$  due to capacitor ESR. The magnitude of the voltage change is again the product of the current change and the capacitor ESR.

It is very important to consider the maximum current step that can exist in the system. If the change in current is large enough, it is possible that the instantaneous voltage drop on  $V_{IN}$  will exceed the  $V_{IN}$  threshold hysteresis, and the IC will enter a mode of operation resembling an oscillation. As the part turns on, the output current  $I_{OUT}$  will increase, reaching current limit during initial charging. Increasing  $I_{OUT}$  results in a drop at  $V_{IN}$  such that the shutdown threshold is reached. The part will turn off, and the load current will decrease. As  $I_{OUT}$  decreases,  $V_{IN}$  will rise and the part will turn on, starting the cycle all over again. This oscillatory operation is most likely at initial startup when the output capacitance is not charged, and in cases where the ramp-up of the  $V_{IN}$  supply is slow. It may also occur during the power transition when the linear regulator turns on and the PFET turns off. A 15 $\mu$ s delay exists between turn-on of the regulator and the AUXDRV pin pulling the gate of the PFET high. This delay prevents "chatter" during the power transitions. During this interval, the linear regulator will attempt to regulate the output voltage as 3.3V. If the output voltage is significantly below 3.3V, the IC will go into current limit while trying to raise  $V_{OUT}$ . It is a short-lived phenomenon and is mentioned here to alert the user that the condition can exist. It is typically not a problem in applications. Careful choice of the PFET switch with respect to  $R_{DS(ON)}$  will minimize the voltage drop which the output must charge through to return to a regulated state. More information is provided in the section on choosing the PFET switch.

If required, using a few capacitors in parallel to increase the bulk charge storage and reduce the ESR should give better performance than using a single input capacitor. Short, straight connections between the power supply and  $V_{IN}$  lead along with careful layout of the PC board ground plane will reduce parasitic inductance effects. Wide  $V_{IN}$  and  $V_{OUT}$  traces will reduce resistive voltage drops.

#### Choosing the PFET Switch

The choice of the external PFET switch is based on two main considerations. First, the PFET should have a very low turn-on threshold. Choosing a switch transistor with  $V_{GS(ON)} \approx 1V$  ensures the PFET will be fully enhanced with only 3.3V of gate drive voltage. Second, the switch transistor should be chosen to have a low  $R_{DS(ON)}$  to minimize the voltage drop due to current flow in the switch. The formula for calculating the maximum allowable on-resistance is

$$R_{DS(ON)(MAX)} = \frac{V_{AUX(MIN)} - V_{OUT(MIN)}}{1.5 \times I_{OUT(MAX)}}$$

where  $V_{AUX(MIN)}$  is the minimum value of the auxiliary supply voltage,  $V_{OUT(MIN)}$  is the minimum allowable output voltage,  $I_{OUT(MAX)}$  is the maximum output current and 1.5 is a "fudge factor" to account for increases in  $R_{DS(ON)}$  due to temperature.

#### Output Voltage Sensing

It is not possible to remotely sense the output voltage of the CS5231-3 since the feedback path to the error amplifier is not externally available. It is important to minimize voltage drops due to metal resistance of high current PC board traces. Such voltage drops can occur in both the supply traces and the return traces.

The following board layout practices will help to minimize output voltage errors:

- Always place the linear regulator as close to both load and output capacitors as possible.
- Always use the widest possible traces to connect the linear regulator to the capacitor network and to the load.
- Connect the load to ground through the widest possible traces.
- Connect the IC ground to the load ground trace at the point where it connects to the load.

#### Current Limit

The CS5231-3 has internal current limit protection. Output current is limited to a typical value of 850mA, even under output short circuit conditions. If the load current drain exceeds the current limit value, the output voltage will be pulled down and will result in an out of regulation condition. The IC does not contain circuitry to report this fault.

#### Thermal Shutdown

The CS5231-3 has internal temperature monitoring circuitry. The output is disabled if junction temperature of the IC reaches a typical value of 180°C. Thermal hysteresis is typi-

cally 25°C and allows the IC to recover from a thermal fault without the need for an external reset signal. The monitoring circuitry is located near the composite PNP-NPN output transistor, since this transistor is responsible for most of the on-chip power dissipation. The combination of current limit and thermal shutdown will protect the IC from nearly any fault condition.

#### Reverse Current Protection

During normal system operation, the auxiliary drive circuitry will maintain voltage on the  $V_{OUT}$  pin when  $V_{IN}$  is absent. IC reliability and system efficiency are improved by limiting the amount of reverse current that flows from  $V_{OUT}$  to ground and from  $V_{OUT}$  to  $V_{IN}$ . Current flows from  $V_{OUT}$  to ground through the feedback resistor divider that sets up the output voltage. This resistor can range in value from 6k $\Omega$  to about 10k $\Omega$ , and roughly 500 $\mu$ A will flow in the typical case. Current flow from  $V_{OUT}$  to  $V_{IN}$  will be limited to leakage current after the IC shuts down. On-chip RC time constants are such that the output transistor should be turned off well before  $V_{IN}$  drops below the  $V_{OUT}$  voltage.

#### Calculating Power Dissipation and Heatsink Requirements

Most linear regulators operate under conditions that result in high on-chip power dissipation. This results in high junction temperatures. Since the IC has a thermal shutdown feature, ensuring the regulator will operate correctly under normal conditions is an important design consideration. Some heatsinking will usually be required.

Thermal characteristics of an IC depend on four parameters: ambient temperature ( $T_A$  in °C), power dissipation ( $P_D$  in watts), thermal resistance from the die to the ambient air ( $\theta_{JA}$  in °C per watt) and junction temperature ( $T_J$  in °C). The maximum junction temperature is calculated from the formula below:

$$T_{J(MAX)} = T_{A(MAX)} + (\theta_{JA}) (P_{D(MAX)})$$

Maximum ambient temperature and power dissipation are determined by the design, while  $\theta_{JA}$  is dependent on the package manufacturer. The maximum junction temperature for operation of the CS5231-3 within specification is 150°C. The maximum power dissipation of a linear regulator is given as

$$P_{D(MAX)} = (V_{in(MAX)} - V_{OUT(MIN)}) (I_{LOAD(MAX)}) + (V_{IN(MAX)}) (I_{GND(MAX)})$$

where  $I_{GND(MAX)}$  is the IC bias current.

It is possible to change the effective value of  $\theta_{JA}$  by adding a heatsink to the design. A heatsink serves in some manner to raise the effective area of the package, thus improving the flow of heat from the package into the surrounding air. Each material in the path of heat flow has its own characteristic thermal resistance, all measured in °C per watt. The thermal resistances are summed to determine the total thermal resistance between the die junction and air. There are three components of interest: junction-to-case thermal resistance ( $\theta_{JC}$ ), case-to-heatsink thermal resistance ( $\theta_{CS}$ )

and heatsink-to-air thermal resistance ( $\theta_{SA}$ ). The resulting equation for junction-to-air thermal resistance is

$$\theta_{JA} = \theta_{JC} + \theta_{CS} + \theta_{SA}$$

The values of  $\theta_{JC}$  for both packages of the CS5231-3 are provided in the Packaging Information section of this data sheet. The value of  $\theta_{CS}$  can be considered zero, since heat is conducted out of the D<sup>2</sup>PAK package by the IC leads and the tab, and out of the SOIC package by its IC leads that are soldered directly to the PC board.

Modification of  $\theta_{SA}$  is the primary means of thermal management. For surface mount components, this means modifying the amount of trace metal that connects to the IC.

The thermal capacity of PC board traces is dependent on how much copper area is used, whether or not the IC is in direct contact with the metal, whether or not the metal surface is coated with some type of sealant, and whether or not there is airflow across the PC board. The chart provided below shows heatsinking capability of a square, single sided copper PC board trace. The area is given in square millimeters. It is assumed there is no airflow across the PC board.

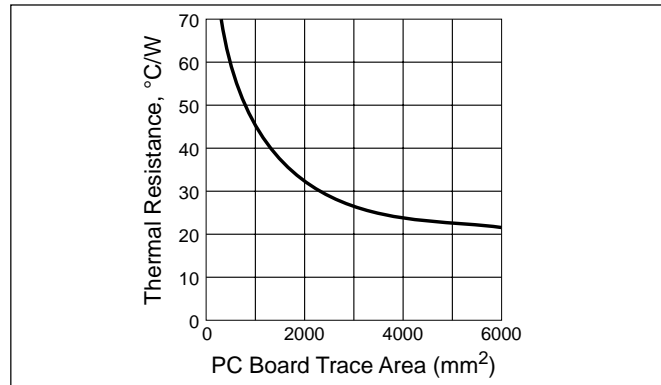


Figure 5: Thermal Resistance Capability of Copper PC Board Metal Traces

#### Typical D<sup>2</sup>PAK PC Board Heatsink Design

A typical design of the PC board surface area needed for the D<sup>2</sup>PAK package is shown on page 10. Calculations were made assuming  $V_{IN(MAX)} = 5.25V$ ,  $V_{OUT(MIN)} = 3.266V$ ,  $I_{OUT(MAX)} = 500mA$ ,  $I_{GND(MAX)} = 5mA$  and  $T_A = 70^\circ C$ .

$$P_D = (5.25V - 3.266V) (0.5A) + (5.25V) (0.005A) = 1018mW$$

Maximum temperature rise  $\Delta T = T_{J(MAX)} - T_A = 150^\circ C - 70^\circ C = 80^\circ C$ .

$$\theta_{JA} \text{ (worst case)} = \Delta T / P_D = 80^\circ C / 1.018W = 78.56^\circ C / W$$

First, we determine the need for heatsinking. If we assume the maximum  $\theta_{JA} = 50^\circ C / W$  for the D<sup>2</sup>PAK, the maximum temperature rise is found to be

$$\Delta T = (P_D) (\theta_{JA}) = (1.018W) (50^\circ C / W) = 50.9^\circ C$$

This is less than the maximum specified operating junction temperature of 125°C, and no heatsinking is required. Since the D<sup>2</sup>PAK has a large tab, mounting this part to the



PC board by soldering both tab and leads will provide superior performance with no PC board area penalty.

### Typical 8 Lead Fused Lead SOIC Design

We first determine the need for a heat sink for the 8 Lead SOIC package at a load of 500mA. Using the dissipation from the D<sup>2</sup>PAK example of 1018mW and the  $\theta_{JA}$  of the SOIC package of 110°C/W gives a temperature rise of 112°C. Adding this to an ambient temperature of 70°C gives 182°C junction temperature. This is an excessive temperature rise but it can be reduced by adding additional cooling in the form of added surface area of copper on the PCB. Using the relationship of maximum temperature rise of

$$\Delta T_{JA} = T_{J(MAX)} - T_A = 150^\circ\text{C} - 70^\circ\text{C} = 80^\circ\text{C}.$$

We calculate the thermal resistance allowed from junction to air:

$$\theta_{JA} \text{ (worst case)} = \Delta T_{JA} / P_D = 80^\circ\text{C} / 1.018\text{W} = 79.6^\circ\text{C/W}.$$

The thermal resistance from the die to the leads (case) is 25°C/W. Subtracting these two numbers gives the allowable thermal resistance from case to ambient:

$$\theta_{CA} = \theta_{JA} - \theta_{JC} = 79.6^\circ\text{C/W} - 25^\circ\text{C/W} = 54.6^\circ\text{C/W}$$

The thermal resistance of this copper area will be 54.6°C/W. We now look at Figure 5 and find the PCB trace area that will be less than 54.5°C/W. Examination shows that 750mm<sup>2</sup> of copper will provide cooling for this part. This would be the SOIC part with the center 4 ground leads soldered to pads in the center of a copper area about 27mm × 27mm. A lower dissipation or the addition of air-flow could result in a smaller required surface area.

### Description

The CS5231-3 application circuit has been implemented as shown in the following pages. The schematic, bill of materials and printed circuit board artwork can be used to build the circuit. The design is very simple and consists of two capacitors, a p-channel FET and the CS5231-3. Five turret pins are provided for connection of supplies, meters, oscilloscope probes and loads. The CS5231-3 power supply management solution is implemented in an area less than 1.5 square inches. Due to the simplicity of the design, output current must be derated if the CS5231-3 is operated at  $V_{IN}$  voltages greater than 7V. Figure 6 provides the derating curve on a maximum power dissipation if heatsink is added. Operating at higher power dissipation without heatsink may result in a thermal shutdown condition.

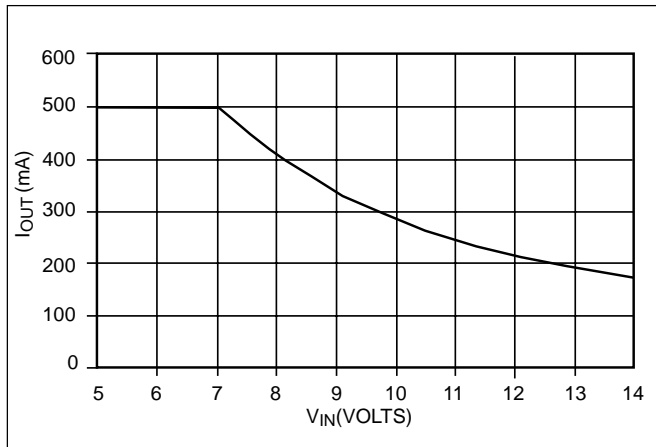


Figure 6: Demo Board Output Current Derating vs  $V_{IN}$

### The $V_{IN}$ Connection

The  $V_{IN}$  connection is denoted as such on the PC board. The maximum input voltage to the IC is 14V before damage to the IC is possible. However, the specification range for the IC is  $4.75\text{V} < V_{IN} < 6\text{V}$ .

### The Gnd Connection

The Gnd connection ties the IC power return to two turret pins. The extra turret pin provides for connection of multiple instrument grounds to the demonstration board.

### The AuxDrv Connection

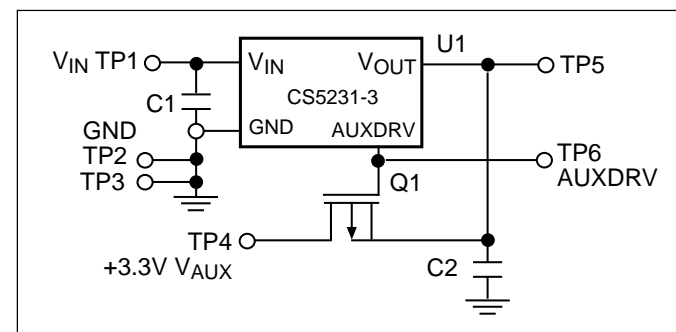
The AuxDrv lead of the CS5231-3 is connected to the gate of the external PFET. This connection is also brought to a turret pin to allow easy connection of an oscilloscope probe for viewing the AuxDrv waveforms.

### The $V_{AUX}$ Connection

The  $V_{AUX}$  turret pin provides a connection point between an external 3.3V supply and the PFET drain.

### The $V_{OUT}$ Connection

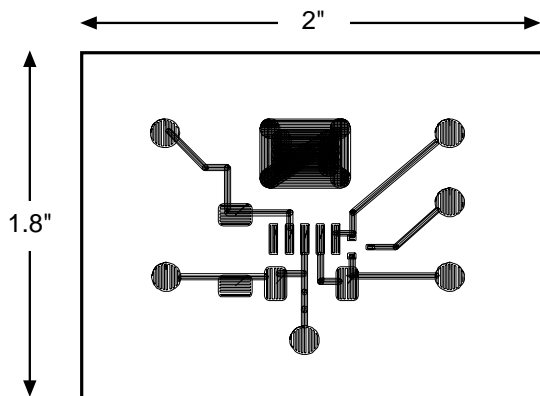
The  $V_{OUT}$  connection is tied to the  $V_{OUT}$  lead of the CS5231-3 and the PFET source. This point provides a convenient point at which some type of lead may be applied.



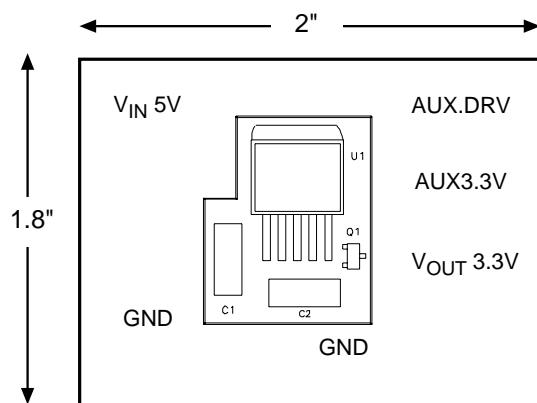
Application Circuit Schematic

### PC Board Layout Artwork

The PC board is a single layer copper design. The layout artwork is reproduced at actual size below.



Top Copper Layer



Top Silk Screen Layer

### Test Descriptions

The startup and supply transition waveforms shown in Figures 1 through 4b were obtained using the application circuit board with a resistive load of  $8.8\Omega$ . This provides a DC load of 375mA when the regulated output voltage is 3.3V. A standard 2A bench supply was used to provide power to the application circuit. The transient response waveforms shown in the Typical Performance Characteristics section were obtained by switching a  $6.3\Omega$  resistor across the output.

### Temperature Performance

The graph below shows thermal performance for the CS5231-3 across the normal operating output current range.

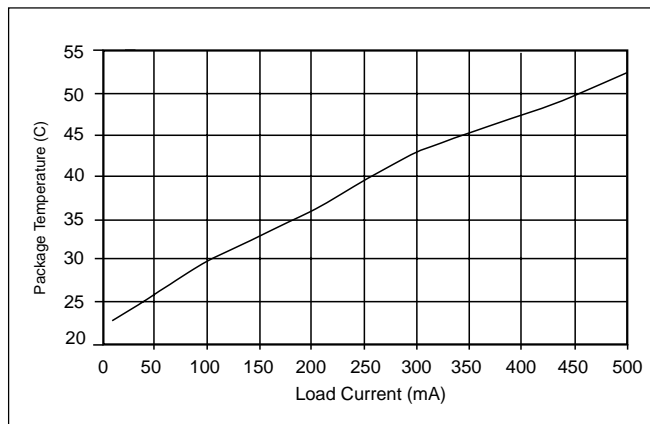


Figure 7: Package Temperature vs Load Current ( $V_{IN} = 5V$ ,  $T_A = 23^\circ C$ )

### PFET $R_{DS(ON)}$ Performance

The graph provided below show typical  $R_{DS(ON)}$  performance for the PFET. The data is provided as  $V_{DS}$  vs  $I_{OUT}$  for different values of  $V_{AUX}$ .

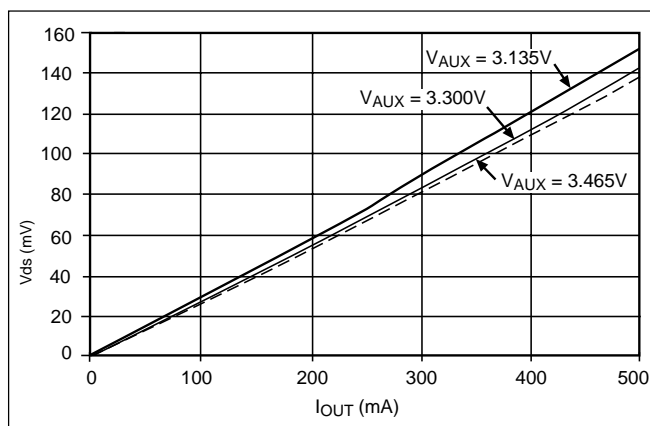


Figure 8: PFET  $V_{DS}$  vs  $I_{OUT}$

## Application Circuit Bill of Materials

Refdes	Description	Part Number	Manufacturer	Contact Information
C1, C2	33 $\mu$ F, 16V tantalum capacitors	TAJD336K016	AVX Corp	www.avxcorp.com 1-843-448-9411
Q1	p-channel FET transistor	MGSF1P02ELT1	Motorola	www.mot-sps.com
U1	Linear regulator with auxiliary	CS5231-3DPS	Cherry Semiconductor	www.cherry-semi.com 1-800-272-3601
T1-T6	Turret pins	40F6023	Newark Electronics	www.newark.com 1-800-463-9275

## Package Specification

## PACKAGE DIMENSIONS IN mm (INCHES)

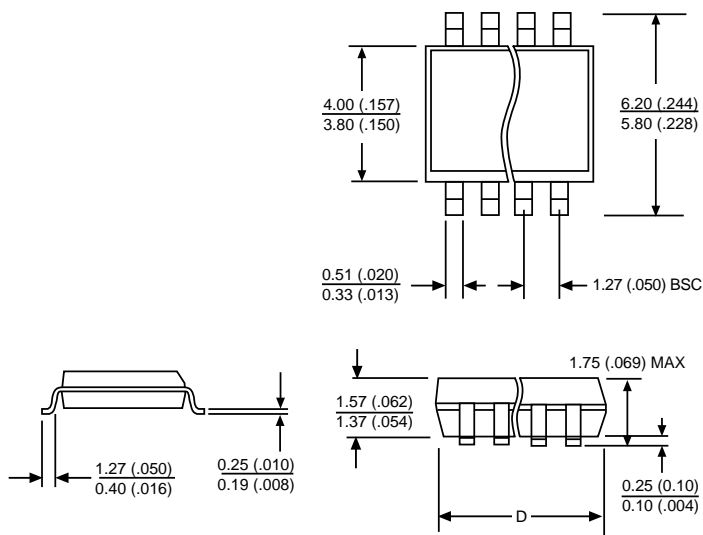
Lead Count	D			
	Metric		English	
	Max	Min	Max	Min
8L SO Narrow (Internally Fused Leads)	5.00	4.80	.197	.189

## PACKAGE THERMAL DATA

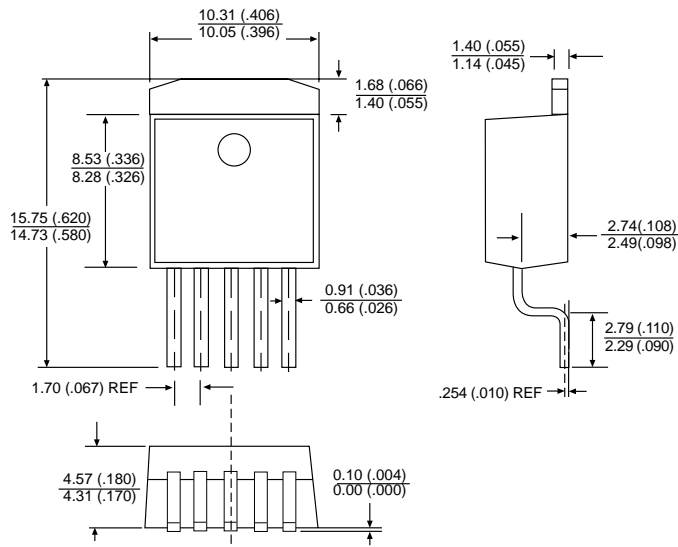
Thermal Data		5Lead D <sup>2</sup> PAK	8 Lead SO Narrow (Internally Fused Leads)	
R <sub>θJC</sub>	typ	2.5	25	°C/W
R <sub>θJA</sub>	typ	10-50*	110	°C/W

\*Depending on thermal properties of substrate.  $R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$

## Surface Mount Narrow Body (D); 150 mil wide



REF: JEDEC MS-012

5 Lead D<sup>2</sup>PAK (DP)

## Ordering Information

Part Number	Description
CS5231-3GDP5	5 Lead D <sup>2</sup> PAK
CS5231-3GDPR5	5 Lead D <sup>2</sup> PAK (tape & reel)
CS5231-3GDF8	8 Lead SO Narrow (Internally Fused Leads)
CS5231-3GDFR8	8 Lead SO Narrow (Internally Fused Leads) (tape & reel)

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